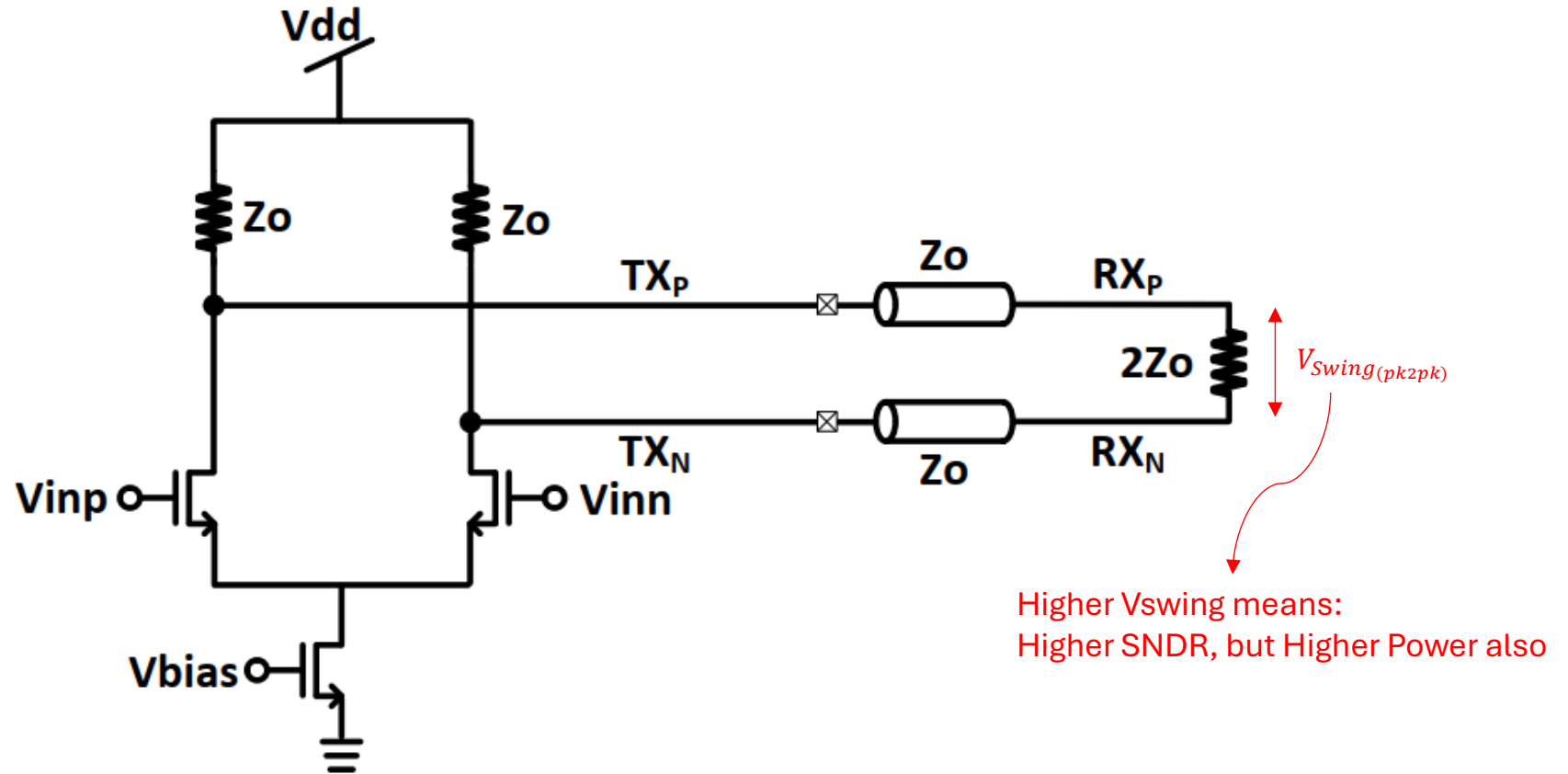


Tx Driver - CML

1 Gbps

Muhammad Aldacher

Current-Mode Logic (CML)



- Current Steering
- Both sides are terminated by 50Ω
- Basic structure in high-performance serial link

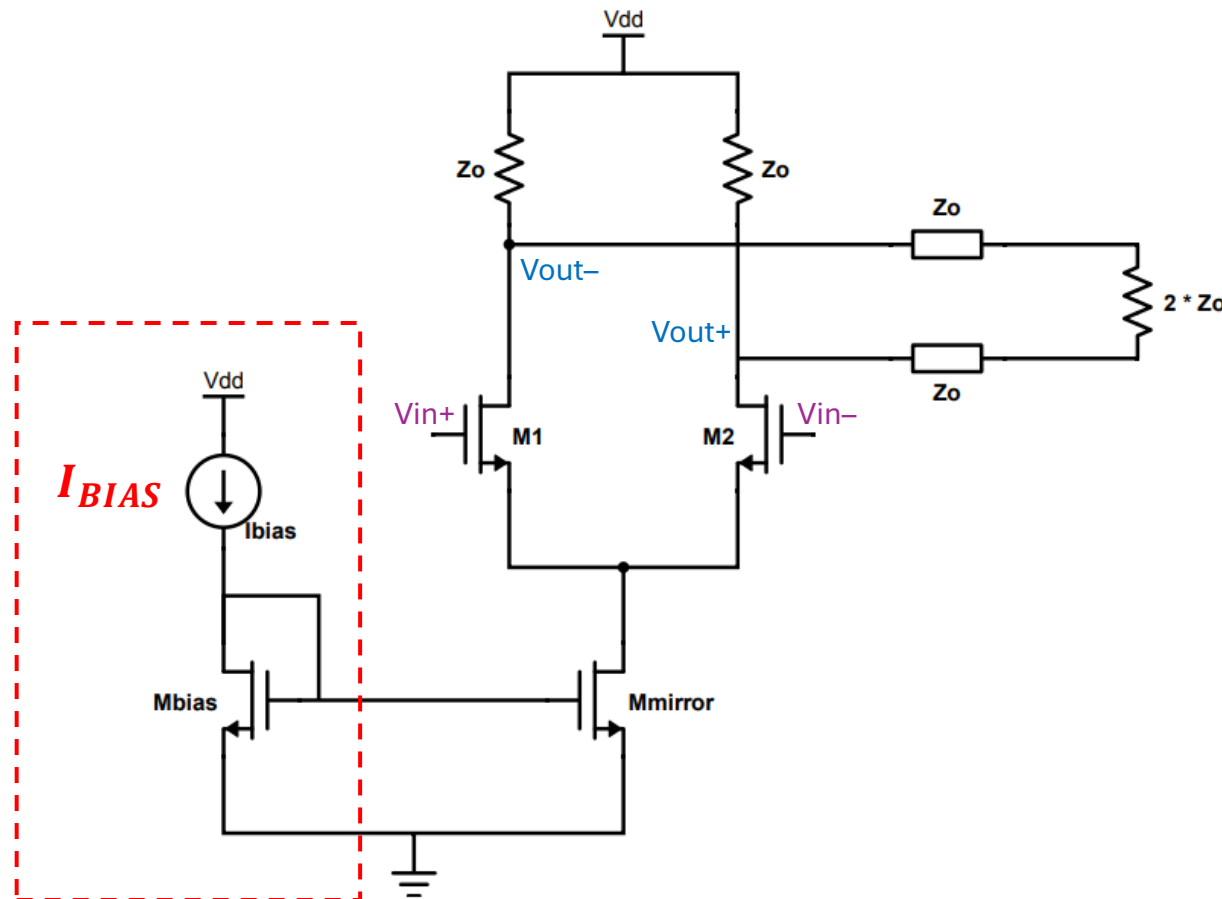
1) Without Replica

$$V_{Swing(pk2pk)} = V_{out+} - V_{out-}$$

$$V_{Swing(pk2pk)} = I_{BIAS} * Z_O$$

For $V_{Swing(pk2pk)} = 500 \text{ mV}$:

$$I_{BIAS} = \frac{500 \text{ mV}}{50 \Omega} = \mathbf{10 \text{ mA}}$$



Device Sizing:

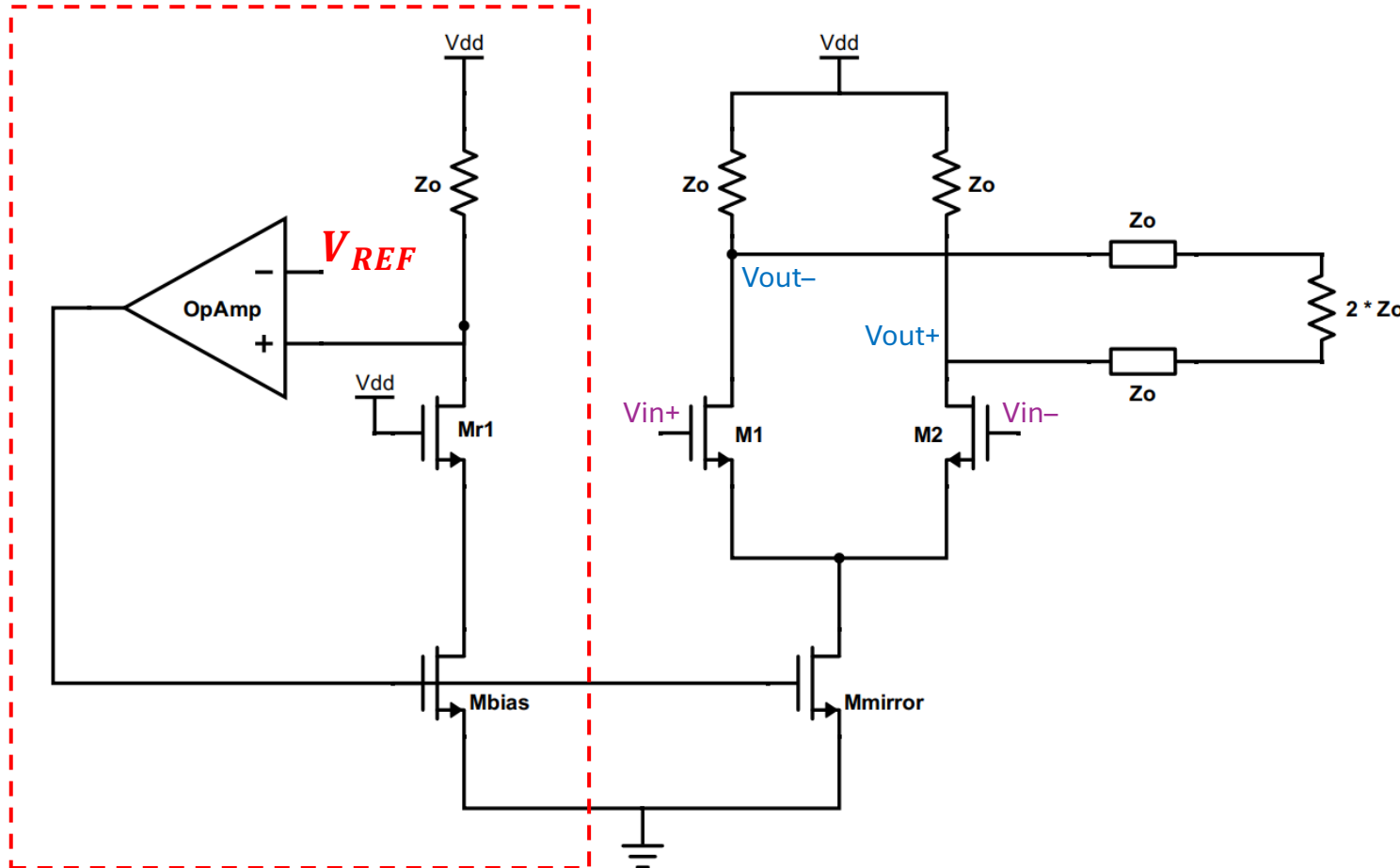
- Input devices (M1 & M2) act as switches, so we should increase W (reducing R_{ON}) to improve headroom.
- Bias devices (Mbias & Mmirror) should have large L to reduce channel length modulation. Also we need to increase their W to reduce their V_{GS} & V_{OV} .

$M1 = M2 :$	$L = L_{MIN}$, $m=100x$
$Mbias = Mmirror :$	$L = 4 * L_{MIN}$, $m=200x$

2) With Replica

$$V_{Ref} = V_{DD} - I_{BIAS} * Z_O$$

$$V_{Swing(pk2pk)} = V_{DD} - V_{REF}$$



For $V_{Swing(pk2pk)} = 500\text{ mV}$:

$$V_{REF} = 1\text{ V} - 250\text{ mV} \\ = 750\text{ mV}$$

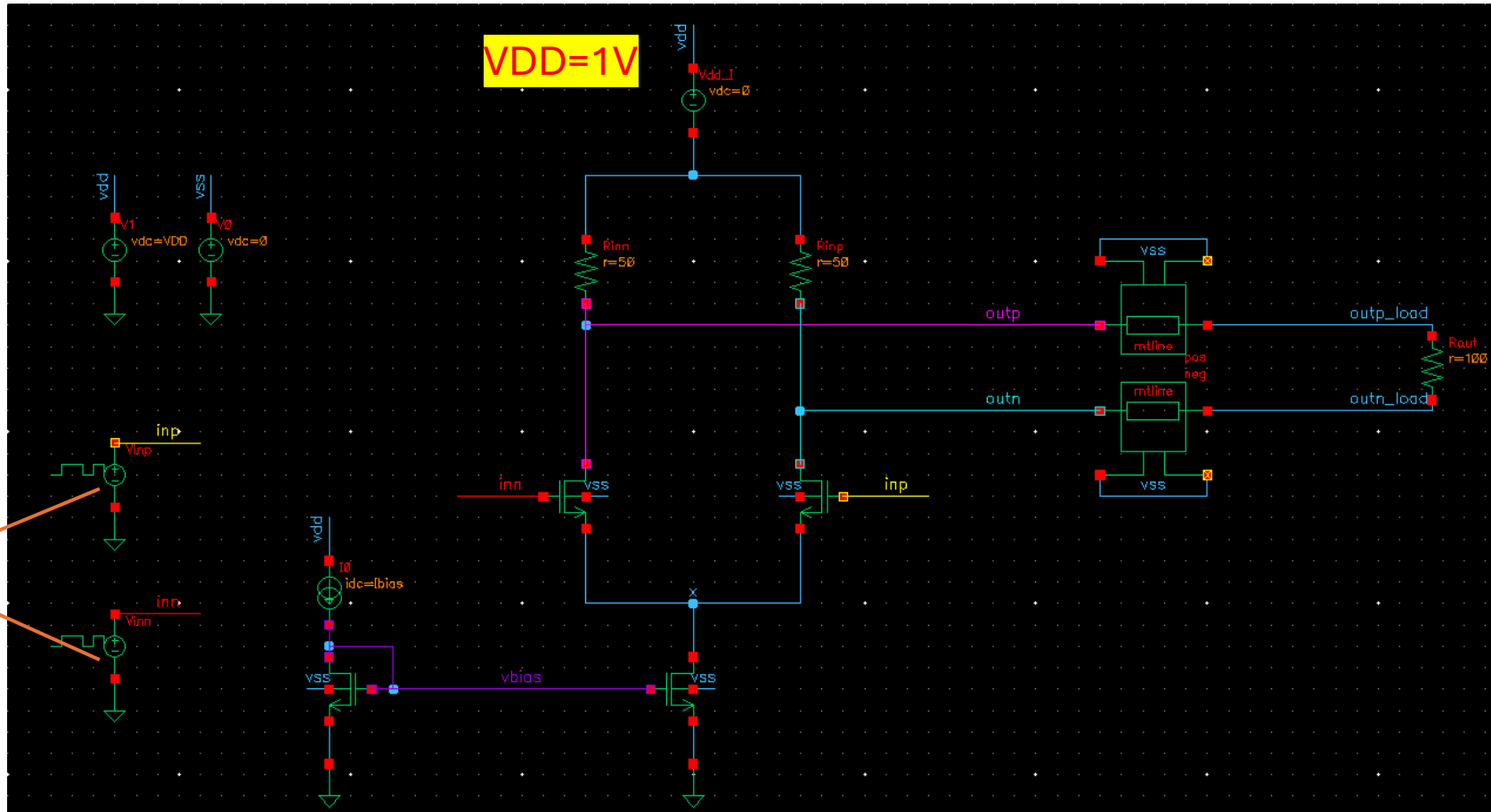
$$\begin{array}{ll} M1 = M2 = Mr1 : & L = L_{MIN} \quad , \quad m=100x \\ M_{bias} = M_{mirror} : & L = 4 * L_{MIN} \quad , \quad m=200x \end{array}$$

Testbenches & Setups

- $V_{DD} = 1V$
- Data-Rate = 1 Gb/s
- $V_{SWING} = 0.5V$ (pk2pk)
- $I_{BIAS} = 10mA$

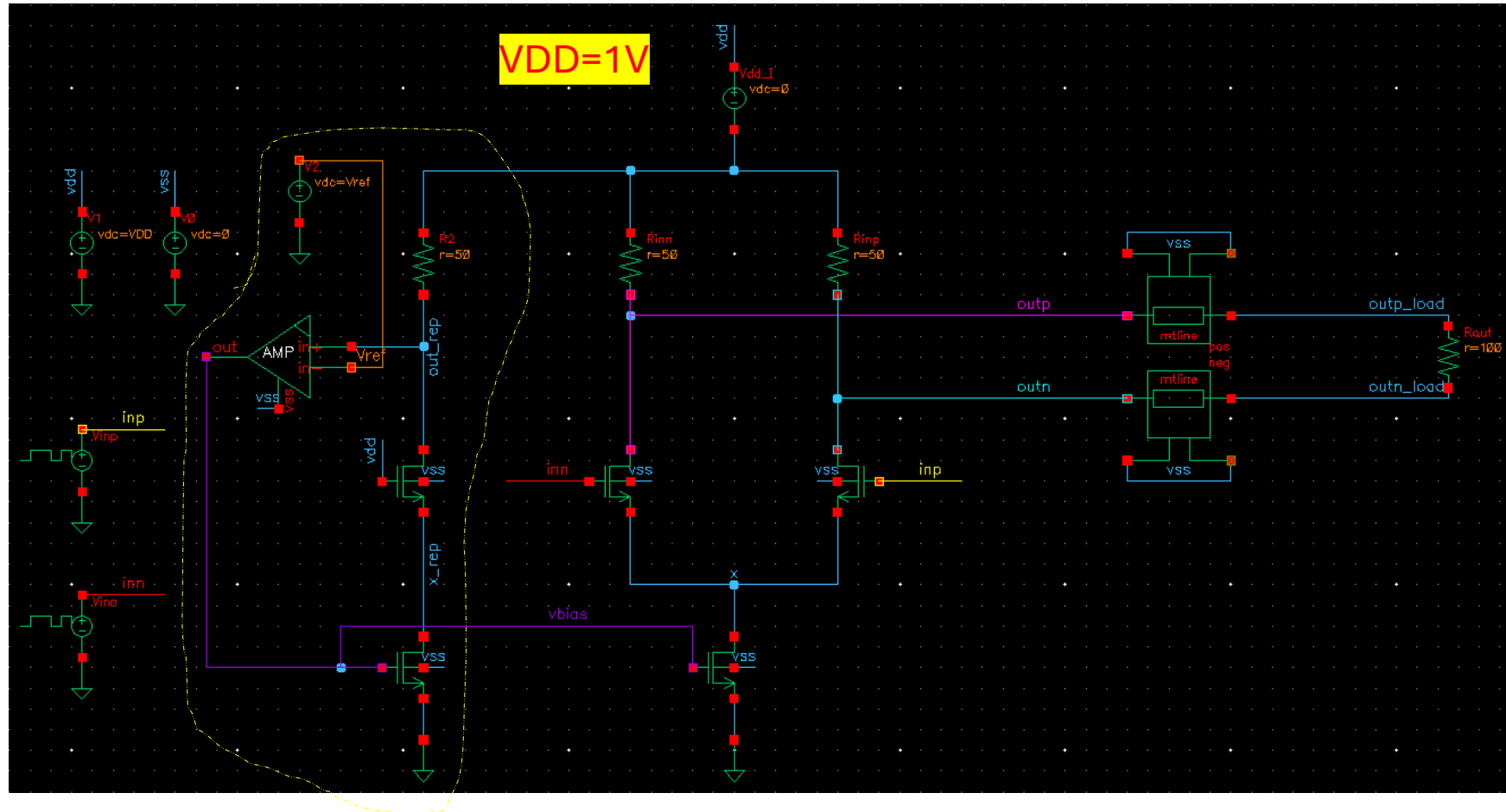
Testbench

A) Without Replica



Testbench

B) With Replica



Channel Settings (mtline)

→ For $Z_0 = 50$ Ohms:

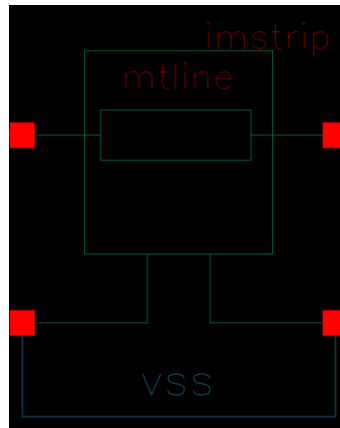
$$Z_0 \approx \frac{87}{\sqrt{\epsilon_r + 1.41}} \ln \left(\frac{5.98 H}{0.8 W + T} \right)$$

Dielectric_const = $\epsilon_r = 4.8$

Dielectric_thickness = $H = 360\mu$

Line_width = $W = 625\mu$

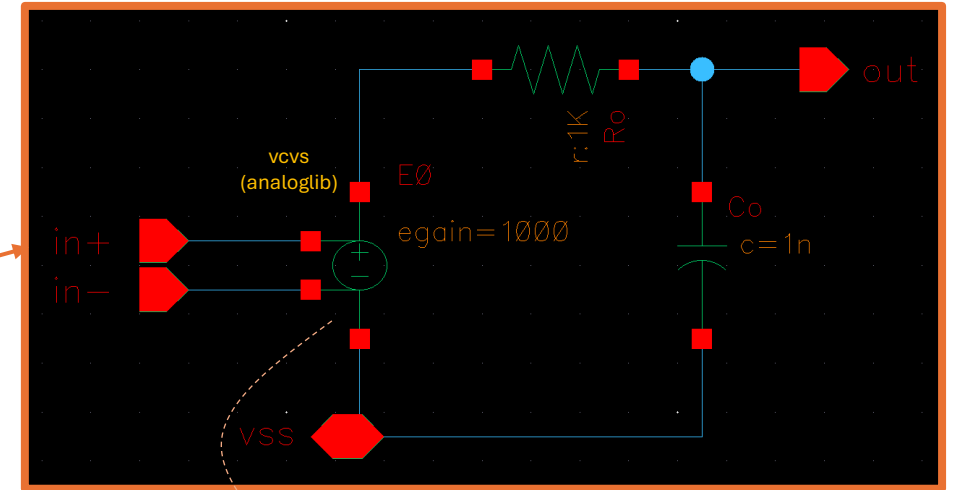
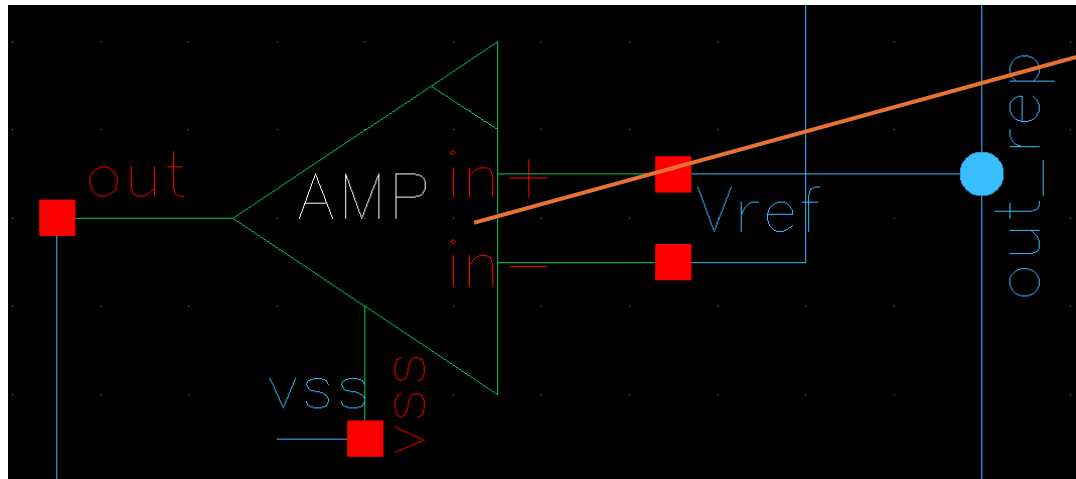
Line_thickness = $T = 17.78\mu$



Library Name	analogLib
Cell Name	mtline

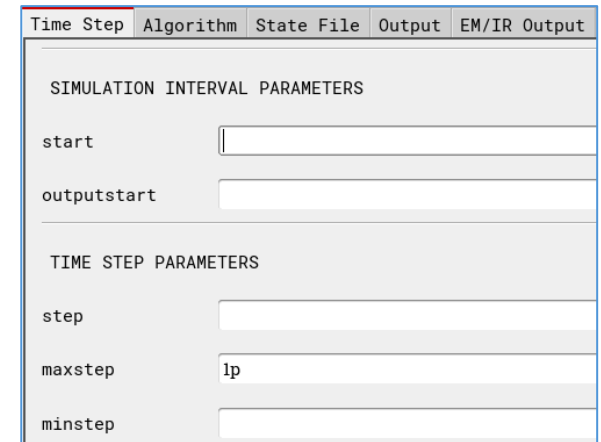
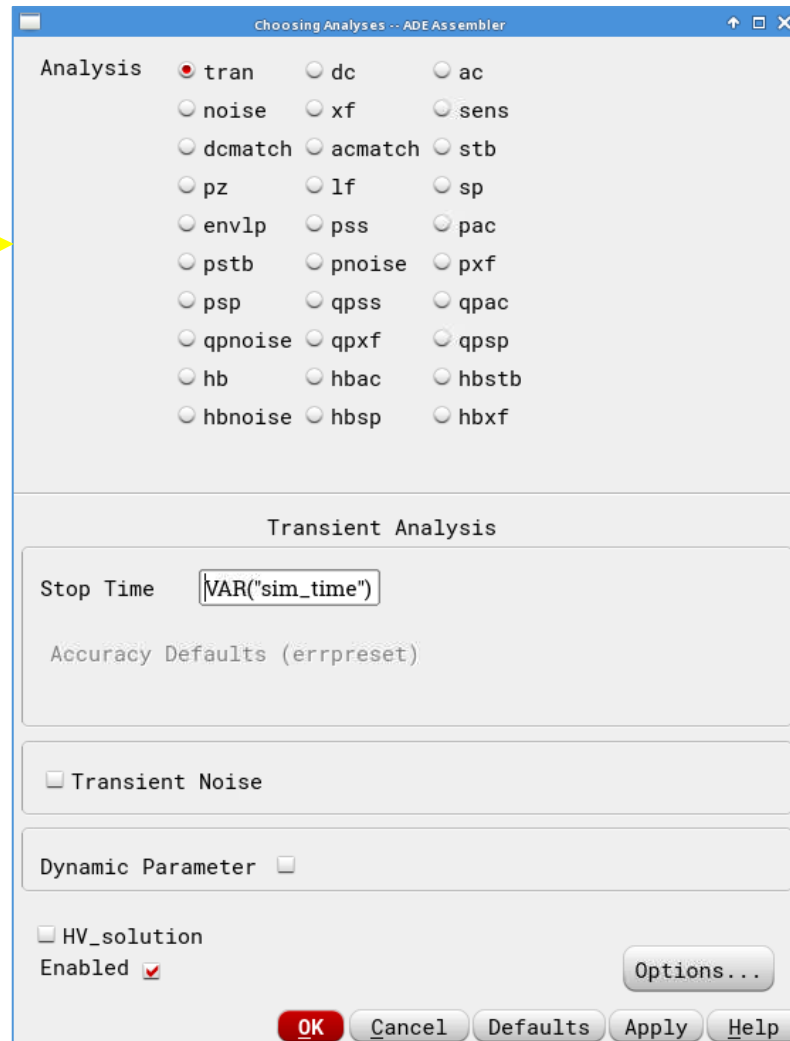
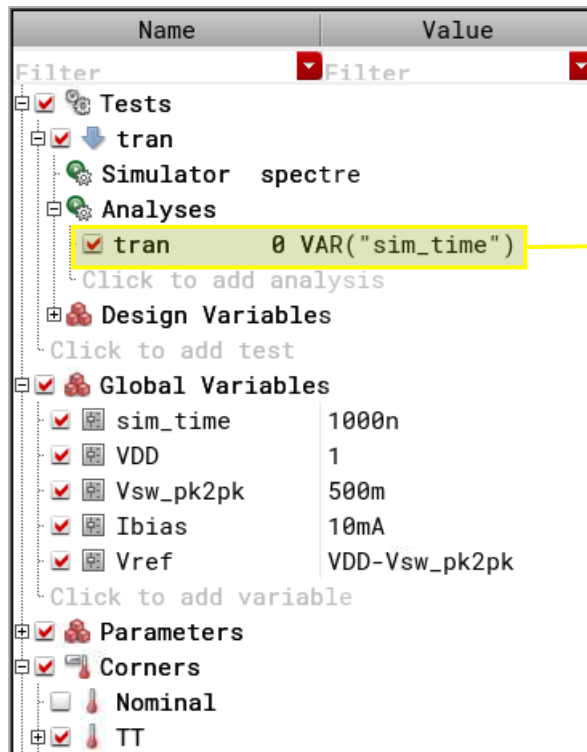
CDF Parameter	Value
Num of lines (excluding ref1)	1
Model name	
Physical length	100m M
Multiplicity factor	1
Max signal frequency	
Type of Input	FieldSolver
Generate noise?	no
Transmission line type	microstrip
Model type	wideband
Rel dielectric const of layer	4.8
Dielectric layer thickness	360u
Signal line width	625u
Signal line thickness	17.78u
Signal line spacing	

Ideal OpAmp



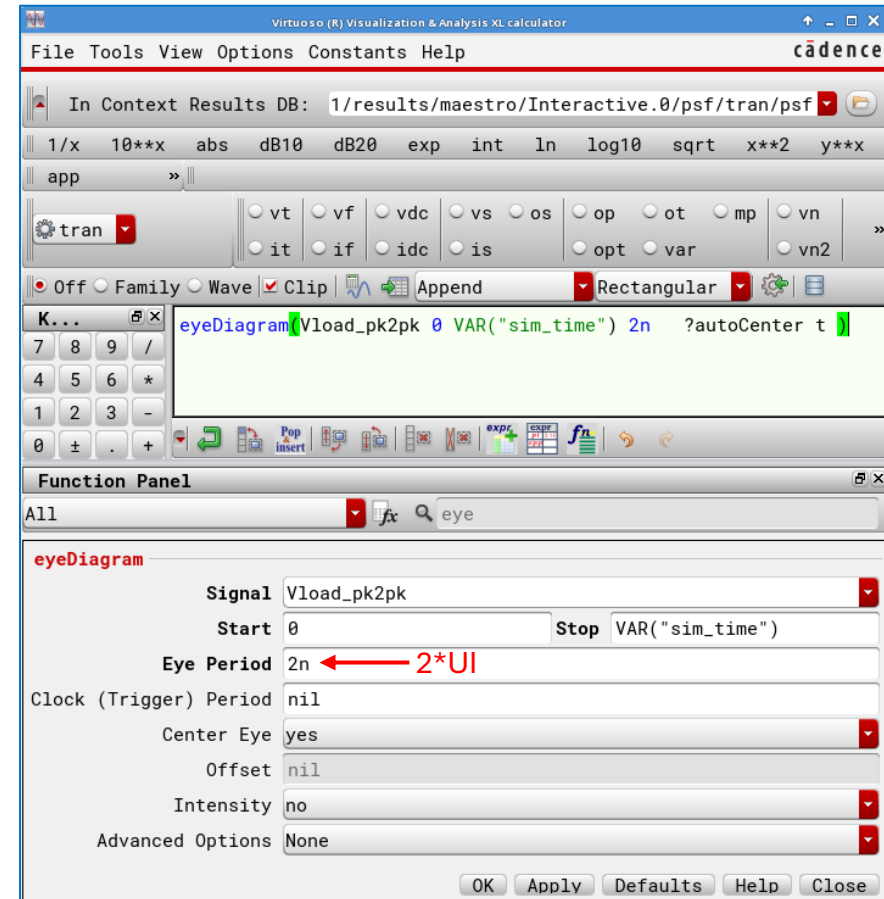
Library Name	analogLib
Cell Name	vcvs
CDF Parameter	
Type of transfer char	<input checked="" type="radio"/> Linear <input type="radio"/> PWL
Smoothing Factor	
Voltage gain	1000
Multiplier	
Maximum Output Voltage	1
Minimum Output Voltage	0

Simulation Setup



Measurements

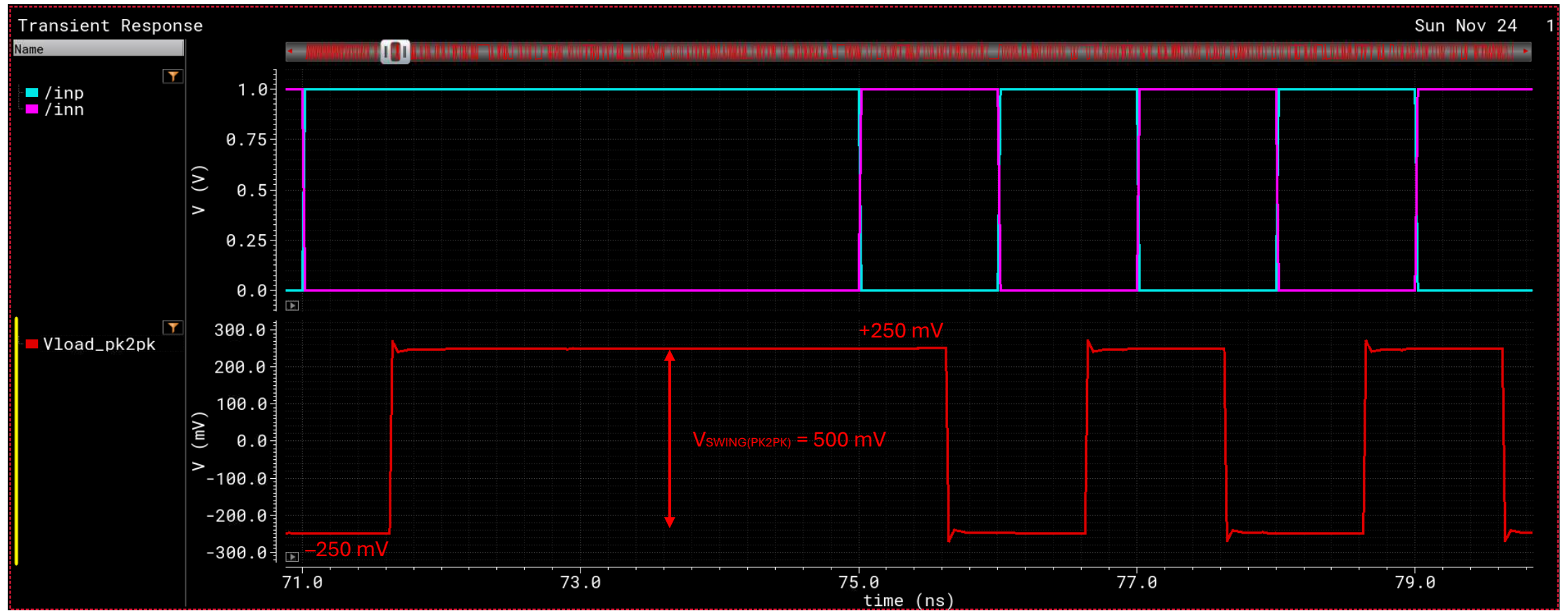
Name	Type	Details	EvalType
Filter	Filter	Filter	Filter
*** Voltages ***	expr		point
	signal	/inp	point
	signal	/inn	point
	signal	/outp	point
	signal	/outn	point
	signal	/outp_load	point
	signal	/outn_load	point
	signal	/x	point
	signal	/vbias	point
	signal	/Vref	point
	signal	/out_rep	point
	signal	/x_rep	point
*** Currents ***	expr		point
/Vdd_I/PLUS_I	signal ...	/Vdd_I/PLUS	point
/Rout/PLUS_I	signal ...	/Rout/PLUS	point
*** Outputs ***	expr		point
Vtxout_pk2pk	expr	(VT("/outp") - VT("/outn"))	point
Vtxout_eye	expr	eyeDiagram(Vtxout_pk2pk 0 VAR("sim_time") 2e-09 ?autoCenter t)	point
Vload_pk2pk	expr	(VT("/outp_load") - VT("/outn_load"))	point
Vload_eye	expr	eyeDiagram(Vload_pk2pk 0 VAR("sim_time") 2e-09 ?autoCenter t)	point



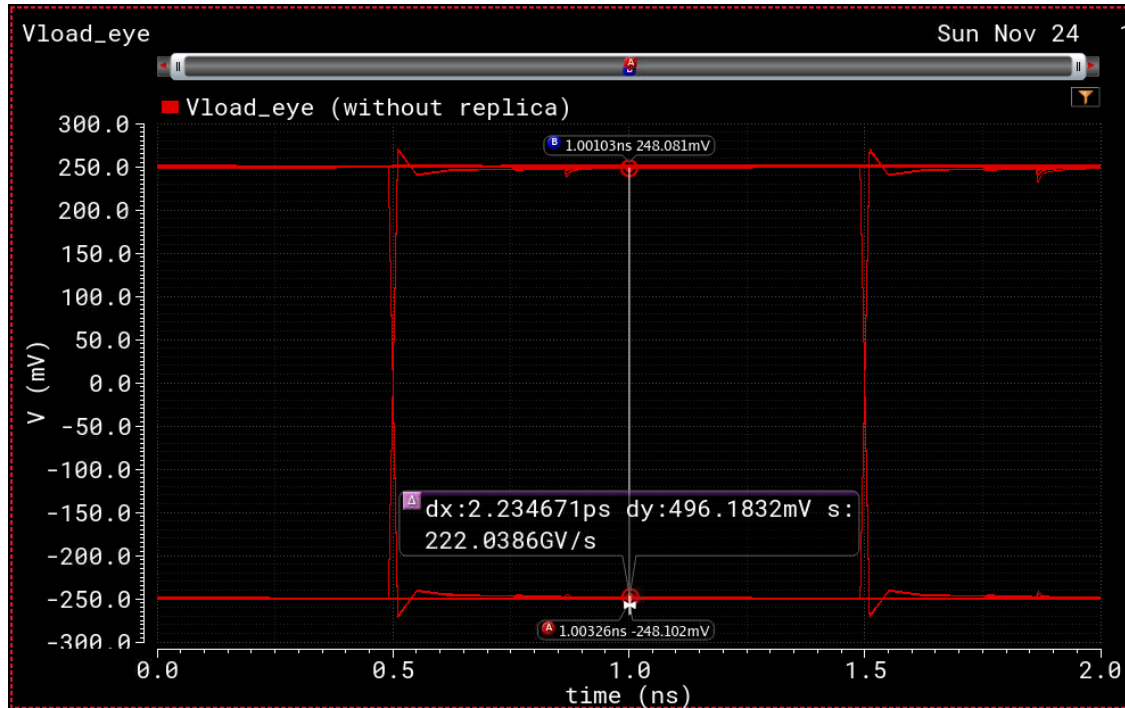
eyeDiagram(VT("/outp_load")-VT("/outn_load") 0 VAR("sim_time") 2n ?autoCenter t)

Simulations & Results

Waveforms

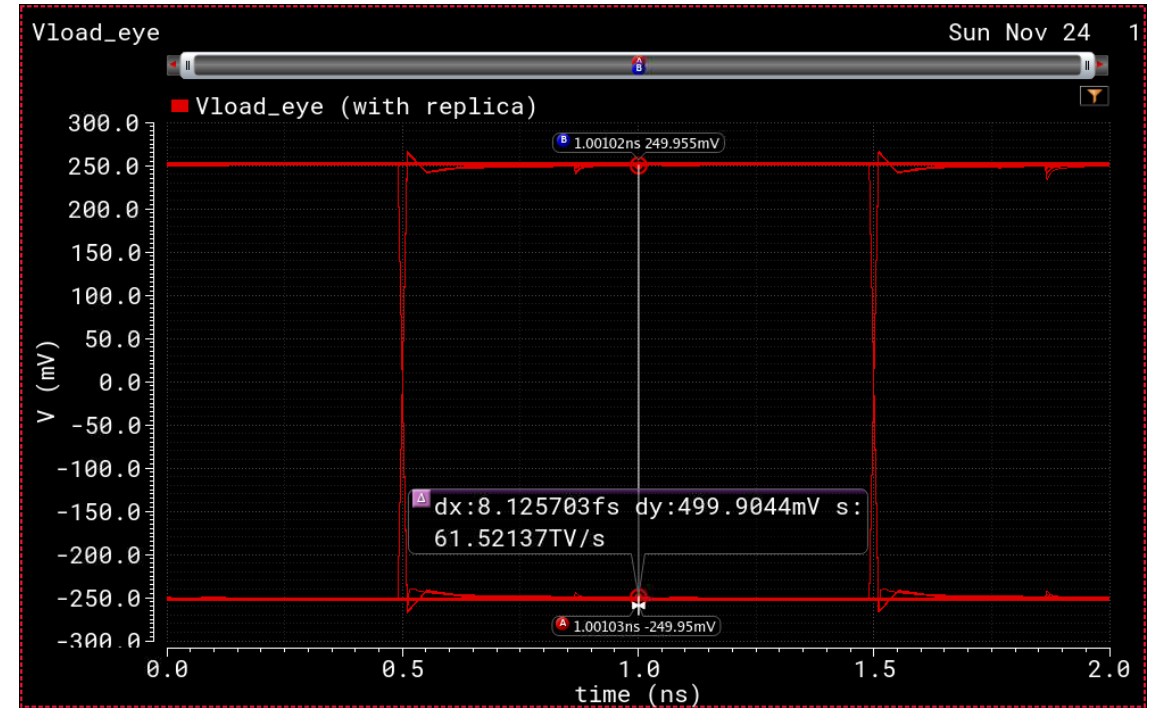


Waveforms (Eye-Diagrams)



No Replica:

$$V_{\text{SW(pk2pk)}} = 496.18 \text{ mV}$$



With Replica:

$$V_{\text{SW(pk2pk)}} = 499.9 \text{ mV}$$

➔ More Accurate Swing, at the expense of an extra branch + additional power drawn by the OpAmp

[\(For more info on how to measure Eye Diagrams\)](#)

Current Consumption

- Total current drawn = 20 mA

(10 mA from main driver + 10 mA from current branch/Replica)